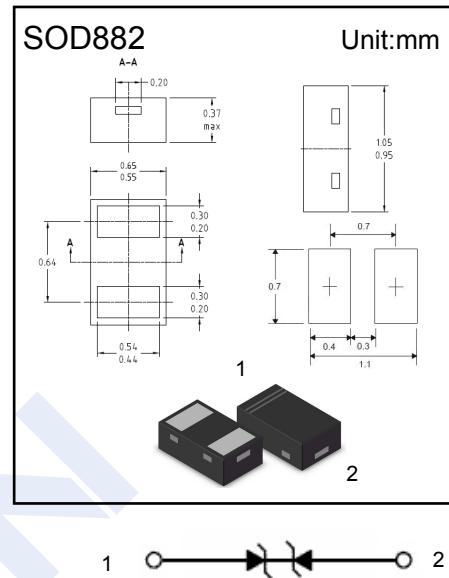


## TVS Diodes

### ESD8D5.0ST5G

#### ■ Features

- Small Body Outline Dimensions
  - Low Body Height
  - Peak Power up to 150 Watts@8 x 20 us Pulse
  - Low Leakage current
  - Response Time is Typically <1ns
- ESD Rating of Class 3(>16kV)per Human



#### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
IEC61000-4-2 (ESD)		± 15	KV
air discharge		± 8	
contact discharge		16	
ESD Voltage		40	A
IEC61000-4-2 (EFT)		150	W
Peak Pulse Power (tp=8/20us)	PPP	150	
Lead Temperature for Soldering During 10s	T <sub>L</sub>	260	°C
Junction Temperature	T <sub>J</sub>	150	
Operating Temperature Range	T <sub>op</sub>	-40 to 125	
Storage Temperature Range	T <sub>stg</sub>	-55 to 150	

#### ■ Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10mA

Device	V <sub>RWM</sub> (V)	I <sub>R1</sub> (uA) @ V <sub>RWM</sub>	I <sub>R2</sub> (uA) @ V <sub>R</sub> =3.5V	V <sub>BR</sub> (V)@ I <sub>T</sub> (Note 1)	I <sub>T</sub>	V <sub>C</sub> (V) @ I <sub>PP</sub> =5 A*	V <sub>C</sub> (V) @ Max I <sub>PP</sub> *	I <sub>PP</sub> (A)*	P <sub>PK</sub> (W)*	C (pF)
	Max	Max	Max	Min	mA	Typ	Max	Max	Max	Typ
ESD8D5.0ST5G	5.0	0.5	0.3	5.6	1.0	11.6	18.6	9.4	174	10

\*Surge current waveform per Figure 1.

1. V<sub>BR</sub> is measured with a pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

#### ■ Marking

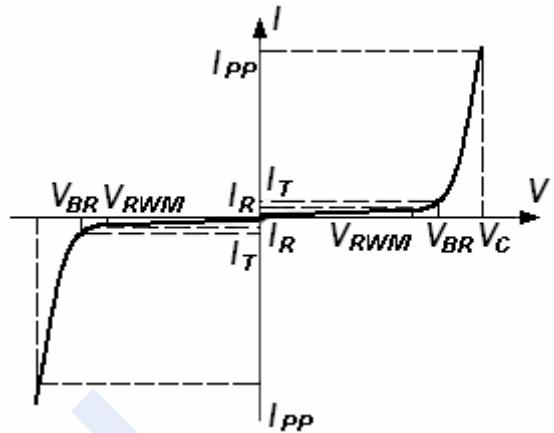
Marking	C
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## TVS Diodes

### ESD8D5.0ST5G

#### ■ Electrical Parameter

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$I_T$	Test Current
$V_{BR}$	Breakdown Voltage @ $I_T$



#### ■ Typical Characteristics

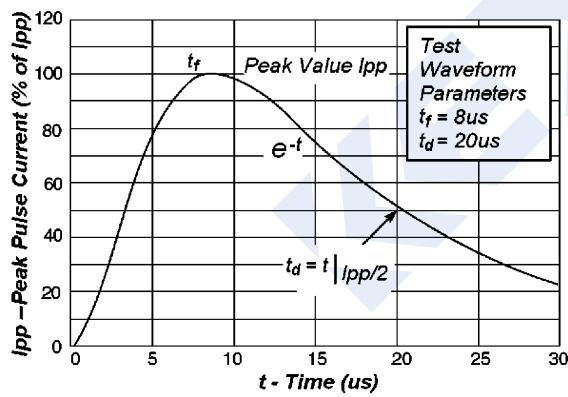


Fig1. Pulse Waveform

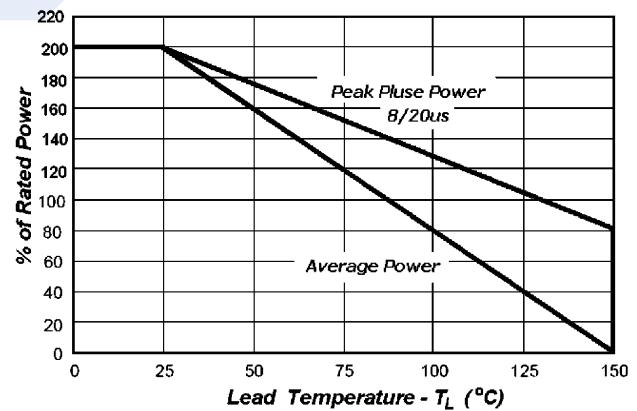


Fig2. Power Derating Curve